

# **High-Voltage Switching Applications**

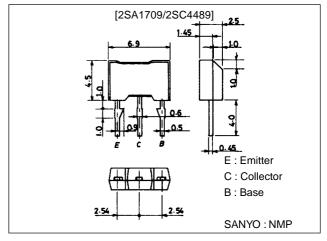
#### **Features**

- · Adoption of FBET, MBIT processes.
- · High breakdown voltage, large current capacity.
- · Fast switching speed.

## **Package Dimensions**

unit:mm

2064



() 2SA1709

## **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		(–)120	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		(–)100	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		(–)6	V
Collector Current	IC		(-)2	Α
Collector Current (Pulse)	I <sub>CP</sub>		(–)3	А
Collector Dissipation	PC		1	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta = 25°C

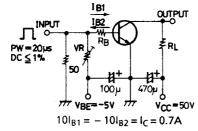
Parameter	Symbol	Conditions	Ratings			Unit
	Syllibol		min	typ	max	Offic
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =(-)100V, I <sub>E</sub> =0			(-)100	nA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0			(-)100	nA
DC Current Gain	hFE	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)100mA	100*		400*	
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)100mA		120		MHz
Collector-to-Emitter Saturation Voltage	VCE(sat)	I <sub>C</sub> =(-)1A, I <sub>B</sub> =(-)100mA		(-0.22)	(-0.6)	V
				0.13	0.4	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =(-)1A, I <sub>B</sub> =(-)100mA		(–)0.85	(–)1.2	V
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =(-)10V, f=1MHz		(25)16		pF

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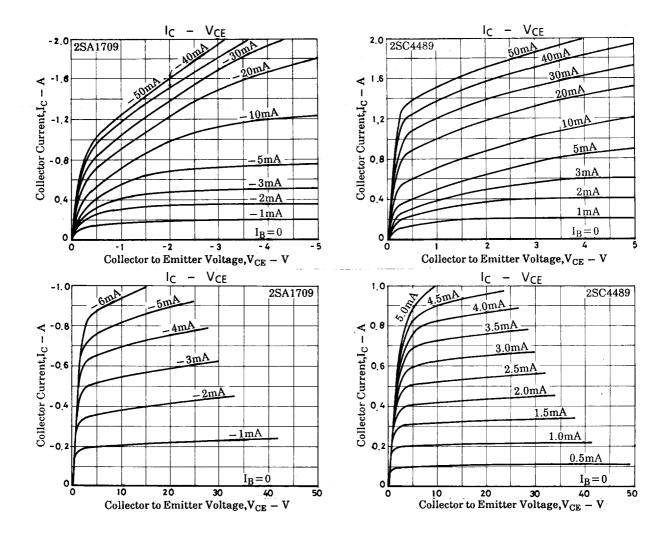
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector-to-Base Breakdown Voltage	V <sub>(BR)</sub> CBO	I <sub>C</sub> =(-)10μA, I <sub>E</sub> =0	(–)120			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =(-)1mA, R <sub>BE</sub> =∞	(–)100			V
Emitter-to-Base Breakdown Voltage	V(BR)CEO	I <sub>E</sub> =(-)10μA, I <sub>C</sub> =0	(–)6			V
Turn-ON Time	ton	See specified Test Circuit		80		ns
Storage Time	t <sub>stg</sub>	See specified Test Circuit		(750)		ns
				1000		ns
Fall Time	t <sub>f</sub>	See specified Test Circuit		(40)50		ns

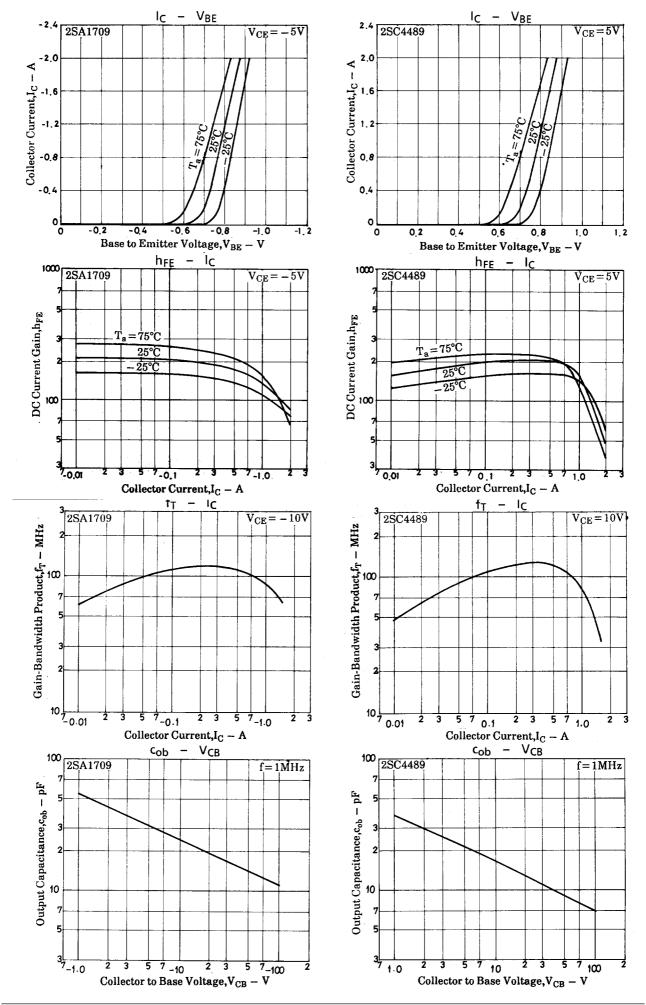
<sup>\* :</sup> The 2SA1709/2SC4489 are classified by 100mA  $h_{\mbox{\scriptsize FE}}$  as follows :

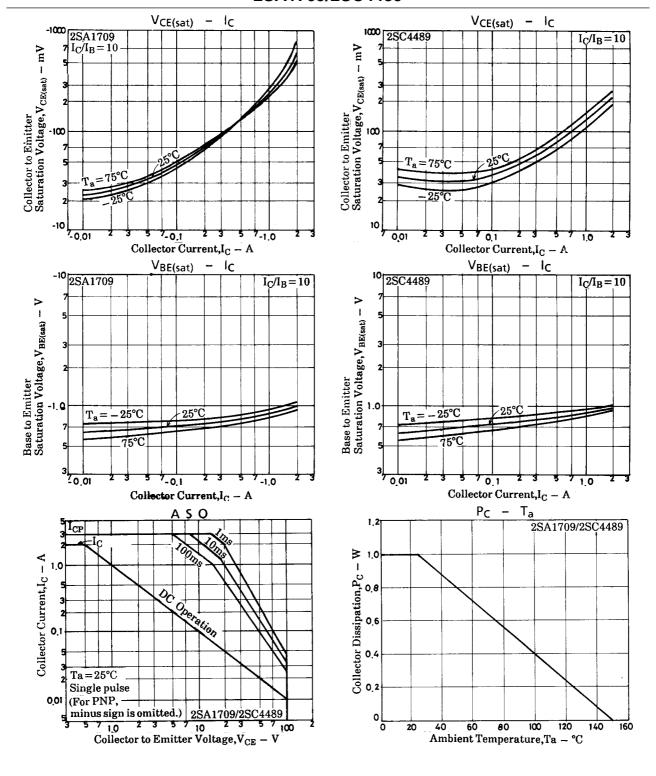
## **Switching Time Test Circuit**



(For PNP, the polarity is reversed.) Unit (resistance :  $\Omega$ , capacitacne : F)







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